

Nanocrystals of Cesium Lead Halide Perovskites (CsPbX₃, X=Cl, Br, and I): Novel Optoelectronic Materials Showing Bright Emission with Wide Color Gamut

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ABSTRACT. Metal halides perovskites, such as hybrid organic-inorganic $\text{CH}_3\text{NH}_3\text{PbI}_3$, are newcomer optoelectronic materials that have attracted enormous attention as solution-deposited absorbing layers in solar cells with power conversion efficiencies reaching 20%. Herein we demonstrate a new avenue for halide perovskites by designing highly luminescent perovskite-based quantum dot materials. We have synthesized monodisperse colloidal nanocubes (4-15 nm edge lengths) of fully inorganic cesium lead halide perovskites (CsPbX_3 , $\text{X}=\text{Cl}$, Br , and I or mixed halide systems Cl/Br and Br/I) using inexpensive commercial precursors. Through compositional modulations and quantum size-effects, the bandgap energies and emission spectra are readily tunable over the entire visible spectral region of 410-700 nm. The photoluminescence of CsPbX_3 nanocrystals is characterized by narrow emission line-widths of 12-42 nm, wide color gamut covering up to 140% of the NTSC color standard, high quantum yields of up to 90% and radiative lifetimes in the range of 1-29 ns. The compelling combination of enhanced optical properties and chemical robustness makes CsPbX_3 nanocrystals appealing for optoelectronic applications, particularly for blue and green spectral regions (410-530 nm), where typical metal chalcogenide-based quantum dots suffer from photodegradation.

KEYWORDS: perovskites, halides, quantum dots, nanocrystals, optoelectronics

TOC Graphic:



Introduction. Colloidal semiconductor nanocrystals (NCs, typically 2-20 nm large), also known as nanocrystal quantum dots (QDs), are being studied intensively as future optoelectronic materials.¹⁻⁴ These QD materials feature a very favorable combination of quantum-size effects, enhancing their optical properties with respect to their bulk counterparts, versatile surface chemistry and a “free” colloidal state, allowing their dispersion into a variety of solvents and matrices and eventual incorporation into various devices. To date, the best developed optoelectronic NCs, in terms of size, shape and composition, are binary and multinary (ternary, quaternary) metal chalcogenide NCs.^{1,5-9} In contrast, the potential of semiconducting metal halides in the form of colloidal NCs remains rather unexplored. In this regard, recent reports on highly efficient photovoltaic devices with certified power conversion efficiencies approaching 20% using hybrid organic-inorganic lead halides MAPbX_3 , ($\text{MA}=\text{CH}_3\text{NH}_3$, $\text{X}=\text{Cl}$, Br , and I) as semiconducting absorber layers are highly stimulating.¹⁰⁻¹⁴

In this study, we turn readers’ attention to a closely related family of materials: all-inorganic cesium lead halide perovskites (CsPbX_3 , $\text{X}=\text{Cl}$, Br , I and mixed Cl/Br and Br/I systems; isostructural to perovskite CaTiO_3 and related oxides). These ternary compounds are far less soluble in common solvents (contrary to MAPbX_3), which is a shortcoming for direct solution processing but a necessary attribute for obtaining these compounds in the form of colloidal NCs. Although the synthesis, crystallography and photoconductivity of direct bandgap CsPbX_3 have been reported more than 50 years ago,¹⁵ they have never been explored in the form of colloidal nanomaterials.

Here we report a facile colloidal synthesis of monodisperse, 4-15 nm CsPbX_3 NCs with cubic shape and cubic perovskite crystal structure. CsPbX_3 NCs exhibit not only compositional bandgap engineering, but owing to the exciton Bohr diameter of up to 12 nm, also exhibit size-

tunability of their bandgap energies through the entire visible spectral region of 410-700 nm. Photoluminescence (PL) of CsPbX₃ NCs is characterized by narrow emission linewidths of 12-42 nm, high quantum yields of 50-90%, short radiative lifetimes of 1-29 ns.

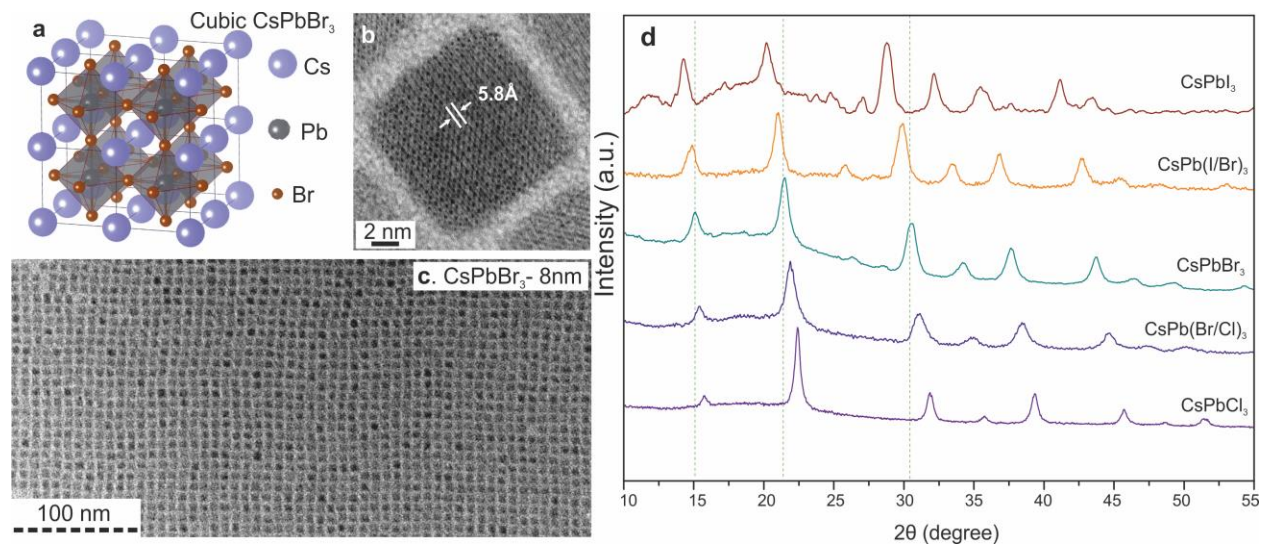


Figure 1. Monodisperse CsPbX₃ NCs and their structural characterization. (a) Schematic of the cubic perovskite lattice; (b,c) typical transmission electron microscopy (TEM) images of CsPbBr₃ NCs; (d) X-ray diffraction patterns for typical ternary and mixed-halide NCs.

Synthesis of monodisperse CsPbX₃ NCs. Our solution-phase synthesis of monodisperse CsPbX₃ NCs (Figure 1) takes advantage of the ionic nature of the chemical bonding in these compounds. Controlled arrested precipitation of Cs⁺, Pb²⁺ and X⁻ ions into CsPbX₃ NCs is obtained by reacting Cs-oleate with a Pb(II)-halide in a high boiling solvent (octadecene) at 140-200 °C [for details, see the Supporting Information (SI)]. A 1:1 mixture of oleylamine and oleic acid are added into octadecene to solubilize PbX₂ and to colloidally stabilize the NCs. As one would expect for an ionic metathesis reaction, the nucleation and growth kinetics are very fast. *In-situ* PL measurements with a CCD-array detector (Figure S1) indicate that the majority of growth occurs within the first 1-3 seconds (faster for heavier halides). Consequently, the size of CsPbX₃ NCs can be most conveniently tuned in the range of 4-15 nm by the reaction temperature

(140-200 °C) rather than by the growth time. Mixed-halide perovskites, *i.e.* CsPb(Cl/Br)₃ and CsPb(Br/I)₃, can be readily produced by combining appropriate ratios of PbX₂ salts. Note that Cl/I perovskites cannot be obtained due to the large difference in ionic radii, in good agreement with the phase diagram for bulk materials.¹⁶ Elemental analyses by energy dispersive X-ray (EDX) spectroscopy and by Rutherford backscattering spectrometry (RBS) confirmed the 1:1:3 atomic ratio for all samples of CsPbX₃ NCs, including mixed-halide systems.

CsPbX₃ are known to crystallize in orthorhombic, tetragonal and cubic polymorphs of the perovskite lattice, with the cubic phase being the high-temperature state for all compounds.¹⁶⁻¹⁸ Interestingly, we find that all CsPbX₃ NCs crystallize in the cubic phase (Figure 1d), which can be attributed to the combined effect of the high synthesis temperature and contributions from the surface energy. For CsPbI₃ NCs, this is very much a metastable state, because bulk material converts into cubic polymorph only above 315 °C. At room temperature, an exclusively PL-inactive orthorhombic phase has been reported for bulk CsPbI₃ (a yellow phase).¹⁶⁻¹⁹ Our first-principles total energy calculations (density functional theory, Figure S2, Table S1 in SI) confirm the bulk cubic CsPbI₃ phase to have 17 kJ/mol higher internal energy than the orthorhombic polymorph (7 kJ/mol for CsPbBr₃). Weak emission centered at ~710nm has been observed from melt-spun bulk CsPbI₃, shortly before recrystallization into the yellow phase.¹⁸ Similarly, our solution synthesis of CsPbI₃ at 305 °C yields cubic-phase 100-200 nm NCs with weak, short-lived emission at 714nm (1.74 eV), highlighting the importance of size reduction for stabilizing the cubic phase and indicating that all CsPbI₃ NCs in Figure 2b (5-15nm in size) exhibit quantum-size effects (*i.e.*, higher band-gap energies due to quantum confinement, as discussed below). Cubic 4-15 nm CsPbI₃ NCs may recrystallize into the yellow phase only upon extended

storage (months), whereas all other compositions of CsPbX_3 NCs appear fully stable in a cubic phase.

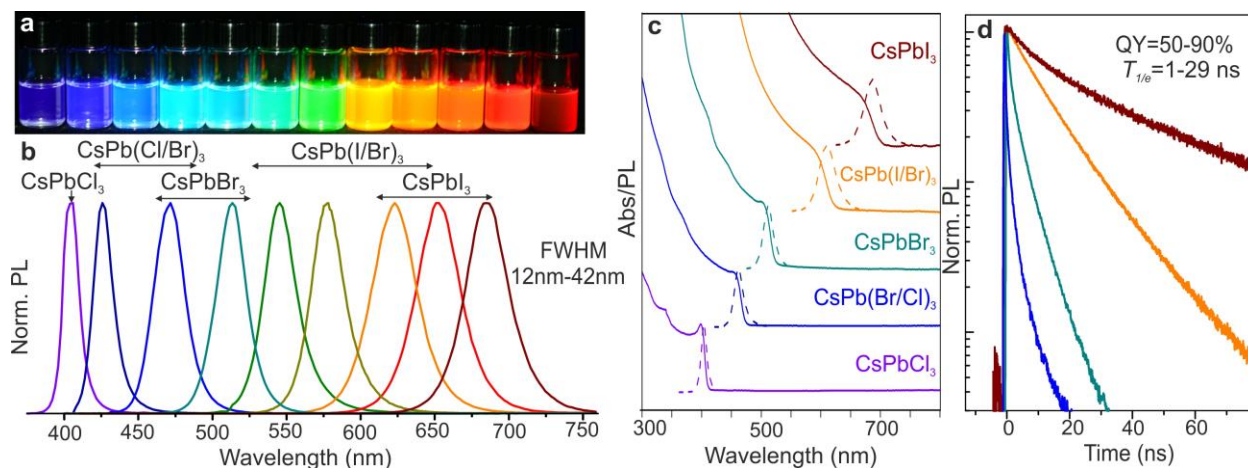


Figure 2. Colloidal perovskite CsPbX_3 NCs ($X=\text{Cl}, \text{Br}, \text{I}$) exhibit size- and composition-tunable bandgap energies covering the entire visible spectral region, with narrow and bright emission: (a) colloidal solutions in toluene, under UV lamp ($\lambda=365$ nm); (b) representative PL spectra ($\lambda_{\text{exc}}=400$ nm for all, but 350 nm for CsPbCl_3 samples); (c) typical optical absorption and PL spectra; (d) time-resolved PL decays for all samples shown in (c), except CsPbCl_3 .

Optical properties of colloidal CsPbX_3 NCs. Optical absorption and emission spectra of colloidal CsPbX_3 NCs (Figure 2b, c) can be tuned over the entire visible spectral region by adjusting their composition (ratio of halides in mixed halide NCs) and particle size (quantum-size effects). Remarkably bright PL of all NCs is characterized by high QY of 50-90% and narrow emission linewidths of 12-42 nm. The combination of these two characteristics had been previously achieved only for core-shell chalcogenide-based QDs such as CdSe/CdS , due to the narrow size distributions of the luminescent CdSe cores, combined with an epitaxially grown, electronically passivating CdS shell.^{5,20} Time-resolved photoluminescence decays of CsPbX_3 NCs (Figure 2d) indicate radiative lifetimes in the range of 1-29 ns, with faster emission for wider-gap NCs. For comparison, decay times of several 100 ns are typically observed in MAPbI_3 (PL peak at 765 nm, FWHM=50 nm)²¹ and 40-400 ns for $\text{MAPbBr}_{3-x}\text{Cl}_x$ ($x=0.6-2$).²²

The very bright emission of CsPbX₃ NCs indicates that, contrary to uncoated chalcogenide NCs, surface dangling bonds do not impart severe mid-gap trap states. This observation is also in good agreement with the high photo-physical quality of hybrid organic-inorganic perovskites (MAPbX₃), despite their low-temperature solution-processing, which is generally considered to cause a high density of structural defects and trap states. In particular, thin-films of MAPbX₃ exhibit relatively high PL QYs of 20-40% at room-temperature²³⁻²⁴ and afford inexpensive photovoltaic devices approaching 20% in power conversion efficiency¹⁰⁻¹² and also electrically-driven light-emitting devices.²⁵

Ternary CsPbX₃ NCs compare favorably to common multinary chalcogenide NCs: both ternary (CuInS₂, CuInSe₂, AgInS₂, and AgInSe₂) and quaternary (CuZnSnS₂ and similar) compounds. CsPbX₃ materials are highly ionic and thus are rather stoichiometric and ordered due to the distinct size and charge of the Cs and Pb ions. This is different from multinary chalcogenide materials that exhibit significant disorder and inhomogeneity in the distribution of cations and anions owing to little difference between the different cationic and anionic sites (all are essentially tetrahedral). In addition, considerable stoichiometric deviations lead to a large density of donor-acceptor states due to various point defects (vacancies, interstitials, etc.) within the band gap, both shallow and deep. These effects eventually lead to absent or weak and broad emission spectra and long multiexponent lifetimes.^{7,26-29}

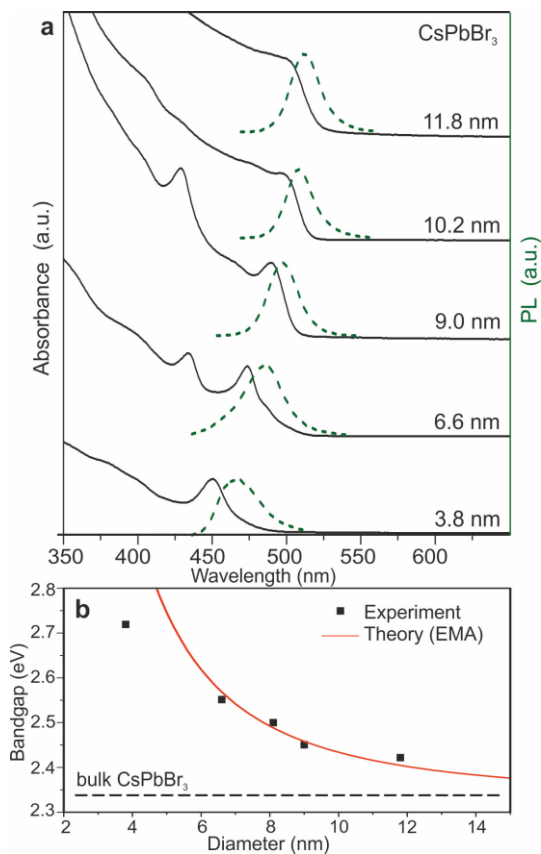


Figure 3. (a) Quantum-size effects in the absorption and emission spectra of 5-12 nm CsPbBr₃ NCs. (b) Experimental vs. theoretical (effective mass approximation, EMA) size dependence of the band-gap energy.

For a colloidal semiconductor NC to exhibit quantum-dot-like properties (shown in Figures 2b and Figure 3), the NC diameter must be comparable or smaller than that of the natural delocalization lengths of an exciton in a bulk semiconductor (*i.e.* the exciton Bohr diameter, a_0). The electronic structure of CsPbX₃ (X = Cl, Br, and I), including scalar relativistic and spin-orbit interactions, was calculated using VASP code,³⁰ and confirms that the upper valence band is formed predominately by the halide p-orbitals and the lower conduction band is formed by the overlap of the Pb p-orbitals (Figures S3 and S4, Tables S2 and S3, in SI). Effective masses of the electrons and holes were estimated from the band dispersion, while the high-frequency dielectric constants were calculated by using density functional perturbation theory.³¹ Within the effective

mass approximation (EMA),³² the effective Bohr diameter of a Wannier-Mott exciton and the binding energies were estimated for CsPbCl₃ (5 nm, 75 meV), CsPbBr₃ (7 nm, 40 meV) and CsPbI₃ (12 nm, 20 meV). Similarly, in closely-related hybrid perovskite MAPbI₃, small exciton binding energies of ≤ 25 meV have been suggested computationally³³⁻³⁵ and found experimentally.³⁶ For comparison, the typical exciton binding energies in organic semiconductors are above 100 meV. The confinement energy ($\Delta E = \hbar^2\pi^2/2m^*r^2$, where r is the particle radius and m^* is the reduced mass of the exciton) provides an estimate for the blue shift of the emission peak and absorption edge, and is in good agreement with the experimental observations (Figure 3b).

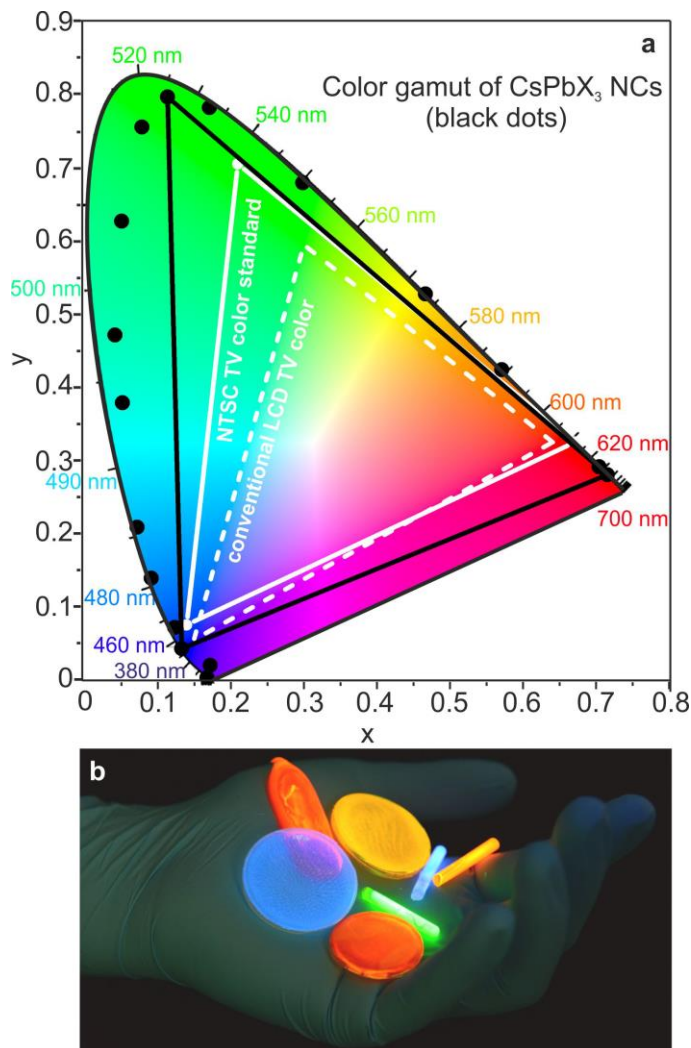


Figure 4. (a) Emission from CsPbX₃ NCs (black data points) plotted on CIE chromaticity coordinates and compared to most common color standards (LCD TV, dashed white triangle, and NTSC TV, solid white triangle). Radiant Imaging Color Calculator software from Radiant Zemax (<http://www.radiantzemax.com>) was used to map the colors. (b) Photograph ($\lambda_{\text{exc}}=365$ nm) of highly luminescent CsPbX₃ NCs-PMMA polymer monoliths obtained with Irgacure 819 as photo-initiator for polymerization.

Recently, highly luminescent semiconductor NCs based on Cd-chalcogenides have inspired innovative optoelectronic applications such as color-conversion LEDs, color-enhancers in backlight applications (e.g., Sony's 2013 Triluminos LCD displays) and solid-state lighting.^{4,37-38} Compared to conventional rare-earth phosphors or organic polymers and dyes, NCs often show superior quantum efficiency and narrower PL spectra with fine-size tuning of the emission peaks, and hence can produce saturated colors. A CIE chromaticity diagram (introduced by the Commission Internationale de l'Eclairage)³⁹ allows the comparison of the quality of colors by mapping colors visible to the human eye in terms of hue and saturation. For instance, well-optimized core-shell CdSe-based NCs cover $\geq 100\%$ of the NTSC TV color standard (introduced in 1951 by the National Television System Committee).³⁹ Figure 4a shows that CsPbX₃ NCs allow a wide gamut of pure colors as well. Namely, a selected triangle of red, green and blue emitting CsPbX₃ NCs encompasses 140% of the NTSC standard, extending mainly into red and green regions.

Light-emission applications, discussed above, and also luminescent solar concentrators,⁴⁰⁻⁴¹ require solution-processability and miscibility of NC-emitters with organic and inorganic matrix materials. To demonstrate such robustness for CsPbX₃ NCs, we embedded them into poly(methylmetacrylate) (PMMA), yielding composites of excellent optical clarity and with bright emission (Figure 4b). To accomplish this, CsPbX₃ NCs were first dispersed in a liquid monomer (methylmetacrylate, MMA) as a solvent. Besides using known heat-induced

polymerization with radical initiators,⁴¹ we also performed polymerization already at room-temperature by adding a photo-initiator Irgacure 819 (Bis(2,4,6-trimethylbenzoyl)-phenylphosphineoxide),⁴² followed by 1h of UV-curing. We find that the presence of CsPbX₃ NCs increases the rate of photopolymerization, compared to a control experiment with pure MMA. This can be explained by the fact that the luminescence from CsPbX₃ NCs may be reabsorbed by the photoinitiator that has a strong absorption band in the visible spectral region, increasing the rate of polymerization.

Conclusions. In summary, we have presented highly-luminescent colloidal CsPbX₃ NCs (X=Cl, Br, I, and mixed Cl/Br and Br/I systems) with bright (QY=50-90%), stable, spectrally narrow and broadly tunable photoluminescence. Particularly appealing are highly-stable blue and green emitting CsPbX₃ NCs (410-530nm), since the corresponding metal-chalcogenide QDs show reduced chemical and photostability at these wavelengths. In our ongoing experiments we find that this simple synthesis methodology is also applicable to other metal halides with related crystal structures (e.g. CsGeI₃, Cs₃Bi₂I₉, and Cs₂SnI₆, to be published elsewhere). Future studies with these novel QD-materials will concentrate on optoelectronic applications such as lasing, light-emitting diodes, photovoltaics and photon detection.

ASSOCIATED CONTENT

Supporting Information Available: Synthesis details, calculations and additional figures. This material is available free of charge via the Internet at date are provided free of charge at <http://pubs.acs.org>.

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Author Contributions

The manuscript was prepared through the contribution of all co-authors. All authors have given approval to the final version of the manuscript.

Notes

The authors declare no competing financial interest.

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